

Form PTO-1449 INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)	Docket Number (Optional) 3259.1US (91-473.02 RE)	Application Number Not Yet Assigned
	Applicant Dennison et al.	
	Filing Date December 12, 2001	Group Art Unit Unknown

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
TN	4,432,799	02/1984	Salazar	11	11	
TN	4,671,851	06/1987	Beyer et al.	11	11	
TN	4,785,337	11/1988	Kenney	11	11	
TN	4,877,750	10/1989	Okumura	11	11	
TN	4,944,836	07/1990	Beyer et al.	11	11	
TN	5,045,899	09/1991	Arimoto et al.	11	11	
TN	5,150,276	09/1992	Gonzalez et al.	11	11	
TN	5,162,240	11/1992	Dennison et al.	11	11	
TN	5,162,248	11/1992	Dennison et al.	11	11	
TN	5,185,282	02/1993	Lee et al.	11	11	
TN	5,313,089	05/1994	Jones, Jr.	11	11	
TN	5,364,809	11/1994	Kwon et al.	11	11	

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO
TN	0286270	12/1987	JP	11	11		
TN	0074752	03/1989	JP	11	11		
TN	0094554	04/1990	JP	11	11		

OTHER DOCUMENTS

(Including Author, Title, Date, Pertinent Pages, Etc.)

TN		"Stacked Capacitor DRAM Cell with Vertical Fins," IBM TDB, Jul. 1990, pp. 245-247.
TN		Kaga, T., et al., "Crown-Shaped Stacked-Capacitor Cell for 1.5-V Operation 64 Mb Dram's", <u>IEEE Transactions on Electron Devices</u> , vol. 38, No. 2, Feb. 1991, pp. 255-261.
TN		Shinmura, N., et al., "A Stacked Capacitor Cell with Ring Structure", <u>Extended abstracts of the 22nd International Conference on Solid State Devices</u> , pp.833-836, 1990.

EXAMINER <i>T. NGUYEN</i>	DATE CONSIDERED <i>4/17/03</i>
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.